

April 1994 Revised April 1999

# 74VHC4316

# **Quad Analog Switch with Level Translator**

### **General Description**

These devices are digitally controlled analog switches implemented in advanced silicon-gate CMOS technology. These switches have low "on" resistance and low "off" leakages. They are bidirectional switches, thus any analog input may be used as an output and vice-versa. Three supply pins are provided on the 4316 to implement a level translator which enables this circuit to operate with 0V–6V logic levels and up to  $\pm 6V$  analog switch levels. The 4316 also has a common enable input in addition to each switch's control which when HIGH will disable all switches to their off state. All analog inputs and outputs and digital

inputs are protected from electrostatic damage by diodes to  $V_{CC}$  and ground.

#### **Features**

- Typical switch enable time: 20 ns
- Wide analog input voltage range: ±6V
- Low "on" resistance: 50 typ.  $(V_{CC}-V_{EE}=4.5V)$ 30 typ.  $(V_{CC}-V_{EE}=9V)$
- Low quiescent current: 80 µA maximum (74VHC)
- Matched switch characteristics
- Individual switch controls plus a common enable
- Pin functional compatible with 74HC4316

### **Ordering Code:**

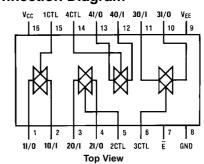
Order Number	Package Number	Package Description
74VHC4316M	M16A	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150 Narrow
74VHC4316WM	M16B	16-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-013, 0.300 Wide
74VHC4316MTC	MTC16	16-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide
74VHC4316N	N16E	16-Lead Plastic Dual-In-Line Package (PDIP), JEDEC MS-001, 0.300 Wide

Surface mount packages are also available on Tape and Reel. Specify by appending the suffix letter "X" to the ordering code

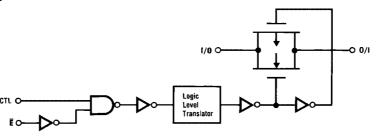
#### **Truth Table**

Inp	outs	Switch		
Ē	CTL	I/O-O/I		
Н	Х	"OFF"		
L	L	"OFF"		
L	Н	"ON"		

#### **Connection Diagram**



## **Logic Diagram**



## **Absolute Maximum Ratings**(Note 1)

Note 2)

Supply Voltage (V <sub>CC</sub> )	-0.5 to $+7.5$ V
Supply Voltage (V <sub>EE</sub> )	+0.5 to $-7.5$ V
DC Control Input Voltage (V <sub>IN</sub> )	$-1.5$ to $V_{CC}+1.5V$
DC Switch I/O Voltage (V <sub>IO</sub> )	$V_{\mbox{\footnotesize EE}}$ –0.5 to $V_{\mbox{\footnotesize CC}}$ +0.5 V
Clamp Diode Current (I <sub>IK</sub> , I <sub>OK</sub> )	±20 mA
DC Output Current, per pin (I <sub>OUT</sub> )	±25 mA
DC $V_{CC}$ or GND Current, per pin ( $I_{CC}$ )	±50 mA
Storage Temperature Range (T <sub>STG</sub> )	-65°C to +150°C
Power Dissipation (P <sub>D</sub> ) (Note 3)	600 mW
S.O. Package only	500 mW
Lead Temperature (T <sub>L</sub> )	
(Soldering 10 seconds)	260°C

# Recommended Operating Conditions

		Min	Max	Units
Supply Voltage	e (V <sub>CC</sub> )	2	6	V
Supply Voltage	e (V <sub>EE</sub> )	0	-6	V
DC Input or O	utput Voltage	0	$V_{CC}$	V
$(V_{IN}, V_{OUT})$				
Operating Ten	nperature Range (T <sub>A</sub> )	-40	+85	°C
Input Rise or F	all Times			
$(t_r, t_f)$	$V_{CC} = 2.0V$		1000	ns
	$V_{CC} = 4.5V$		500	ns
	$V_{CC} = 6.0V$		400	ns
	$V_{CC} = 12.0V$		250	ns

Note 1: Absolute Maximum Ratings are those values beyond which damage to the device may occur.

Note 2: Unless otherwise specified all voltages are referenced to ground.

Note 3: Power Dissipation temperature derating — plastic "N" package: –

## DC Electrical Characteristics (Note 4)

Symbol	Parameter	Conditions	V <sub>EE</sub> V <sub>CC</sub>		T <sub>A</sub> = 25°C		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$	Units
			3	- 60	Typ Gua		anteed Limits	O.I.I.O
V <sub>IH</sub>	Minimum HIGH			2.0V	0 / 7.	1.5	1.5	
	Level Input			4.5V		3.15	3.15	V
	Voltage			6.0V		4.2	4.2	
V <sub>IL</sub>	Maximum LOW			2.0V		0.5	0.5	
	Level Input			4.5V		1.35	1.35	V
1	Voltage			6.0V		1.8	1.8	
R <sub>ON</sub>	Minimum "ON"	$V_{CTL} = V_{IH},$	GND	4.5V	100	170	200	Ω
	Resistance	$I_S = 2.0 \text{ mA}$	-4.5V	4.5V	40	85	105	
	(Note 5)	$V_{IS} = V_{CC}$ to $V_{EE}$	-6.0V	6.0V	30	70	85	
		(Figure 1)						
		V <sub>CTL</sub> = V <sub>IH</sub> ,	GND	2.0V	100	180	215	
		$I_S = 2.0 \text{ mA}$	GND	4.5V	40	80	100	
		$V_{IS} = V_{CC}$ or $V_{EE}$	-4.5V	4.5V	50	60	75	
		(Figure 1)	-6.0V	6.0V	20	40	60	
R <sub>ON</sub>	Maximum "ON"	V <sub>CTL</sub> = V <sub>IH</sub>	GND	4.5V	10	15	20	
	Resistance	$V_{IS} = V_{CC}$ to $V_{EE}$	-4.5V	4.5V	5	10	15	Ω
	Matching		-6.0V	6.0V	5	10	15	
I <sub>IN</sub>	Maximum Control	$V_{IN} = V_{CC}$ or GND	GND	6.0V		±0.1	±1.0	μА
	Input Current							
I <sub>IZ</sub>	Maximum Switch	$V_{OS} = V_{CC}$ or $V_{EE}$						
	"OFF" Leakage	$V_{IS} = V_{EE}$ or $V_{CC}$	GND	6.0V		±30	±300	nA
	Current	$V_{CTL} = V_{IL}$	-6.0V	6.0V		±50	±500	
		(Figure 2)						
I <sub>IZ</sub>	Maximum Switch	$V_{IS} = V_{CC}$ to $V_{EE}$						
	"ON" Leakage	$V_{CTL} = V_{IH}$	GND	6.0V		±20	±75	nA
	Current	V <sub>OS</sub> = OPEN	-6.0V	6.0V		±30	±150	
		(Figure 3)						
I <sub>CC</sub>	Maximum Quiescent	$V_{IN} = V_{CC}$ or GND	GND	6.0V		1.0	10	μА
	Supply Current	$I_{OUT} = 0 \mu A$	-6.0V	6.0V		4.0	40	

Note 4: For a power supply of 5V  $\pm$ 10% the worst case on resistances (R<sub>ON</sub>) occurs for VHC at 4.5V. Thus the 4.5V values should be used when designing with this supply. Worst case V<sub>IH</sub> and V<sub>IL</sub> occur at V<sub>CC</sub> = 5.5V and 4.5V respectively. (The V<sub>IH</sub> value at 5.5V is 3.85V.) The worst case leakage current occurs for CMOS at the higher voltage and so the 5.5V values should be used.

Note 5: At supply voltages (V<sub>CC</sub>-V<sub>EE</sub>) approaching 2V the analog switch on resistance becomes extremely non-linear. Therefore it is recommended that these devices be used to transmit digital only when using these supply voltages.

## **AC Electrical Characteristics**

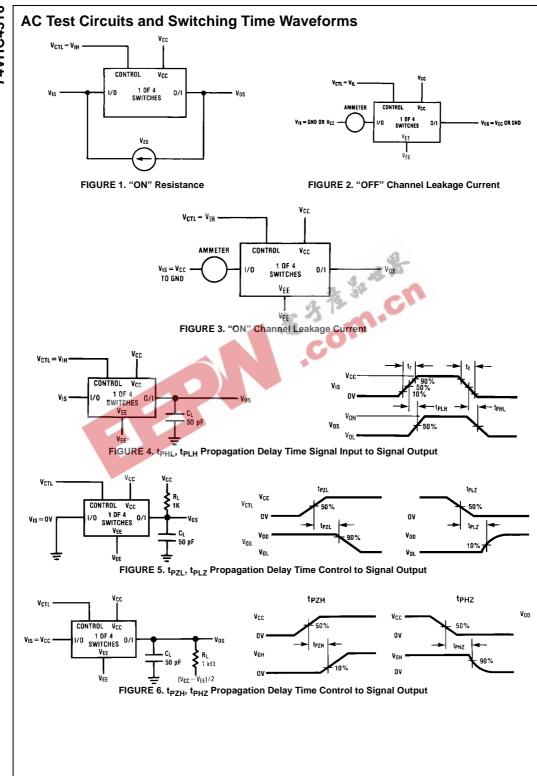
 $V_{CC} = 2.0V - 6.0V$ ,  $V_{EE} = 0V - 6V$ ,  $C_L = 50$  pF unless otherwise specified

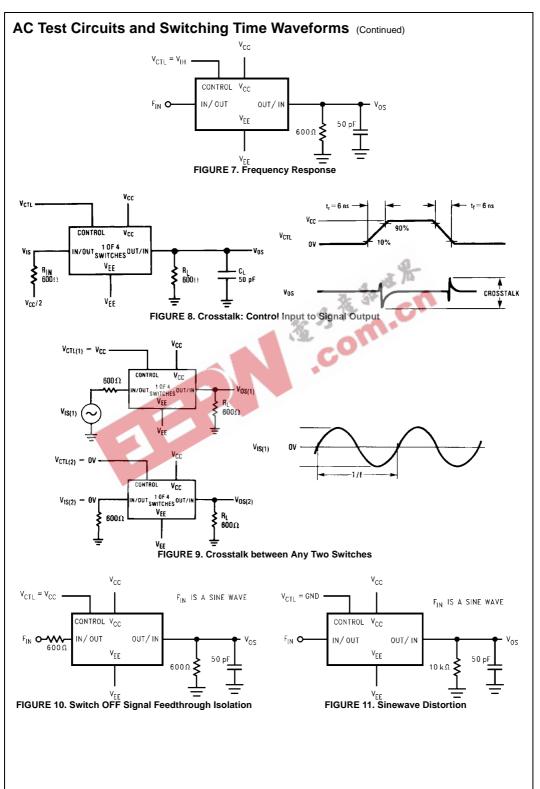
Symbol	Parameter	Conditions	VEE	V <sub>CC</sub>	T <sub>A</sub> =+	-25°C	T <sub>A</sub> =-40°C to +85°C	Units
Cymbol		Conditions	V EE	• 66	Typ Guara		anteed Limits	Ullits
t <sub>PHL</sub> , t <sub>PLH</sub>	Maximum Propagation		GND	3.3V	15	30	37	
	Delay Switch In to		GND	4.5V	5	10	13	ns
	Out		-4.5V	4.5V	4	8	12	
			-6.0V	6.0V	3	7	11	
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Switch Turn	$R_L = 1 k\Omega$	GND	3.3V	25	97	120	
	"ON" Delay		GND	4.5V	20	35	43	ns
	(Control)		-4.5V	4.5V	15	32	39	
			-6.0V	6.0V	14	30	37	
t <sub>PHZ</sub> , t <sub>PLZ</sub>	Maximum Switch Turn	$R_L = 1 k\Omega$	GND	3.3V	35	145	180	
	"OFF" Delay		GND	4.5V	25	50	63	ns
	(Control)		-4.5V	4.5V	20	44	55	
			-6.0V	6.0V	20	44	55	
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Switch		GND	3.3V	27	120	150	
	Turn "ON" Delay		GND	4.5V	20	41	52	ns
	(Enable)		-4.5V	4.5V	19	38	48	
			-6.0V	6.0V	18 🎩	36	45	
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Maximum Switch		GND	3.3V	42	155	190	
	Turn "OFF" Delay		GND	4.5V	28	53	67	ns
	(Enable)		-4.5V	4.5V	23	47	59	
			-6.0V	6.0V	21	47	59	
	Minimum Frequency	$R_L = 600\Omega$ , $V_{IS} = 2V_{PP}$	0V	4.5	40			
	Response (Figure 7)	at (V <sub>CC</sub> -V <sub>EE</sub> /2)	-4.5V	4.5V	100			MHz
	20 log $(V_{OS}/V_{IS}) = -3 dB$	(Note 6)(Note 7)						
	Control to Switch	$R_L = 600\Omega$ , $f = 1 \text{ MHz}$	0V	4.5V	100			
	Feedthrough Noise	C <sub>L</sub> = 50 pF	-4.5V	4.5V	250			mV
	(Figure 8)	(Note 7)(Note 8)						
	Crosstalk Between	$R_L = 600\Omega$ , $f = 1 \text{ MHz}$	0V	4.5V	-52			
	any Two Switches		-4.5V	4.5V	-50			dB
	(Figure 9)							
	Switch OFF Signal	$R_L = 600\Omega$ , $f = 1 \text{ MHz}$						
	Feedthrough	$V_{CTL} = V_{IL}$	0V	4.5V	-42			dB
	Isolation		-4.5V	4.5V	-44			
	(Figure 10)	(Note 7)(Note 8)						
THD	Sinewave Harmonic	$R_L = 10 \text{ K}\Omega$ , $C_L = 50 \text{ pF}$ ,						
	Distortion	f = 1 KHz						%
	(Figure 11)	$V_{IS} = 4 V_{PP}$	0V	4.5V	0.013			
		$V_{IS} = 8 V_{PP}$	-4.5V	4.5V	0.008			
C <sub>IN</sub>	Maximum Control				5			pF
	Input Capacitance							
C <sub>IN</sub>	Maximum Switch				35			pF
	Input Capacitance							
C <sub>IN</sub>	Maximum Feedthrough	V <sub>CTL</sub> = GND			0.5			pF
	Capacitance							
C <sub>PD</sub>	Power Dissipation				15			pF
	Capacitance	1	1	1	1	l	1	ì

Note 6: Adjust 0 dBm for f = 1 kHz (Null R<sub>L</sub>/Ron Attenuation).

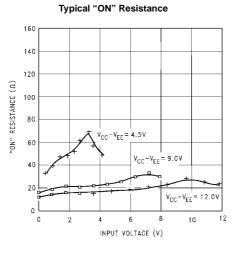
Note 7:  $V_{IS}$  is centered at  $V_{CC} - V_{EE}/2$ .

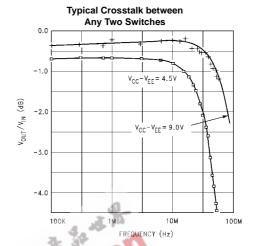
Note 8: Adjust for 0 dBm.

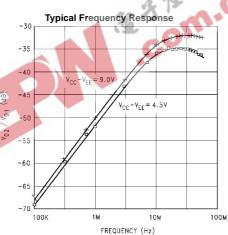




## **Typical Performance Characteristics**

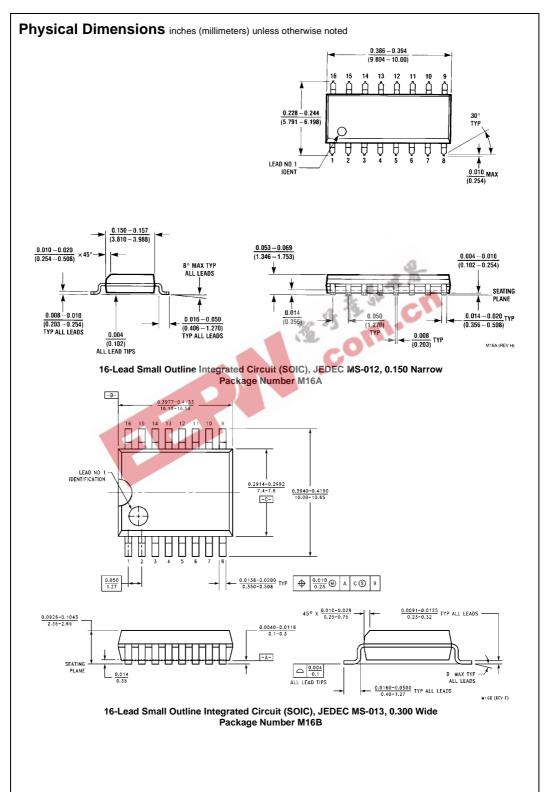


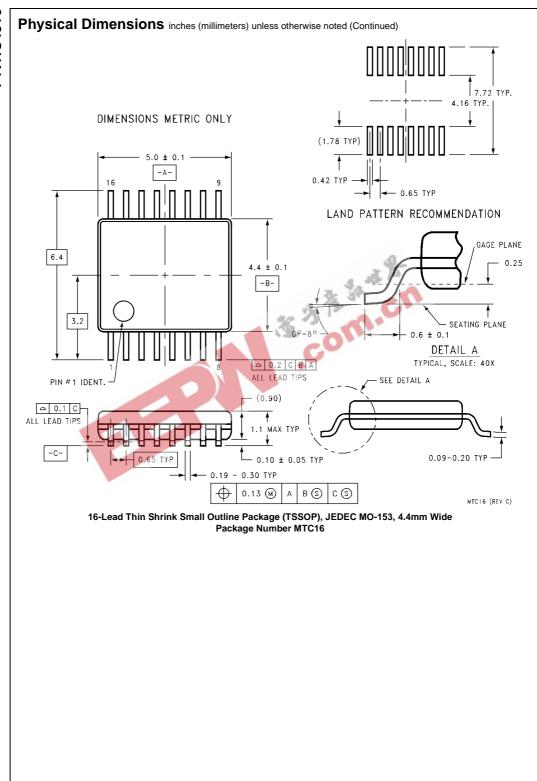


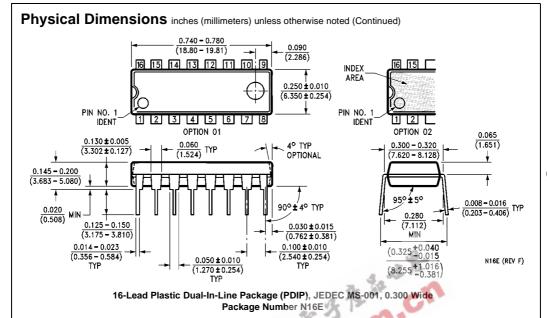


## **Special Considerations**

In certain applications the external load-resistor current may include both  $V_{CC}$  and signal line components. To avoid drawing  $V_{CC}$  current when switch current flows into the analog switch input pins, the voltage drop across the switch must not exceed 0.6V (calculated from the ON resistance).







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